TO-252 ṂṂ Ŀ ̷ ᵍ͡ ǁ ᒉ

Schottky Barrier Diode in a TO-252 Plastic Package.

ᆺ* ᵇ ╡ ╨ ĩ ˥ ı ʌ Ḫ* ᵇ я ں V_F(typ)=0.2V ı Ҷ ȁ ᆺ □ Ӌ ḧ ớ

High Forward Surge Capability, Ultra Low Forward Voltage Drop V_F(typ)=0.2V, Excellent High Temperature Stability.

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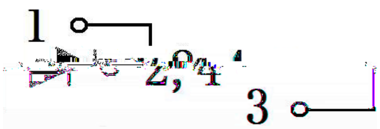
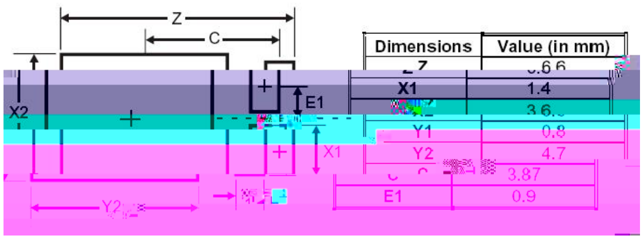
For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.





PIN1 χ Anode PIN 2,4 χ Cathode PIN 3 χ Anode Suggested Pad layout

ŏ м ٦ ب ˝ See Marking Instructions.

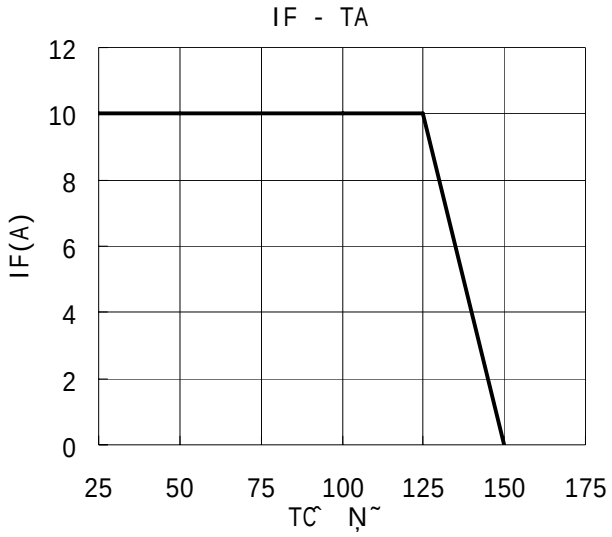
v ¨Ω Parameter	ч N Symbol	¨Ω Ö Rating	D Ц Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage Peak Reverse Voltage	V_{RRM} V_{RWM} V_{RM}	45	V
RMS Reverse voltage	$V_{R(RMS)}$	31.5	V
Average Rectified Output Current	I_O	10	A
Non-Repetitive Peak Forward Surge Current	I_{FSM}	250	A
Junction Temperature Range	$T_{j\ MAX}$	150	
Storage Temperature Range	T_{stg}	-55˙ 150	
Typical Thermal Resistance	$R_{\theta JA}$˝ Note 1˝	73	/W

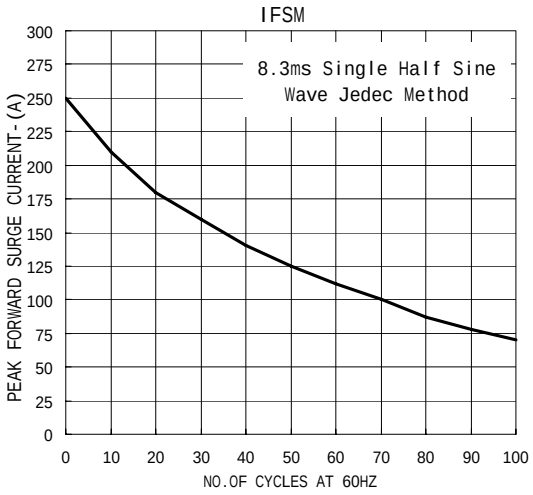
v ¨Ω Parameter	ч N Symbol	╨ :┆ Ţ Test Conditions	ѡ ņ Ö Min	Ɛ ʒ Ö Typ	ѡ ᶻ Ö Max	D Ц Unit
Reverse Voltage	V_R	I_R=0.5mA	45			V
Forward voltage	V_F	I_F=2A T_J=25		0.33	0.38	V
		I_F=2A T_J=125		0.20		V
		I_F=10A T_J=25		0.42	0.46	V
		I_F=10A T_J=125		0.35		V
Instantaneous Reverse Current	I_R˝ Note 2˝	V_R=45V T_J=25		0.06	0.12	mA
		V_R=45V T_J=100			12	mA
		V_R=45V T_J=125			50	mA

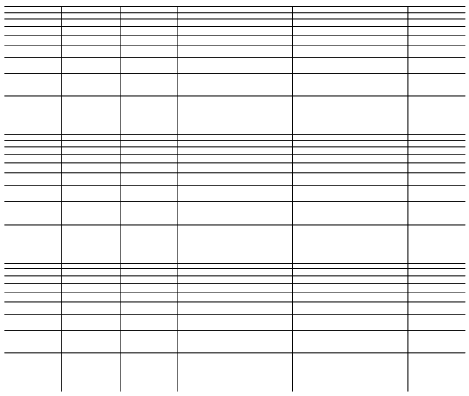
├2Notes'

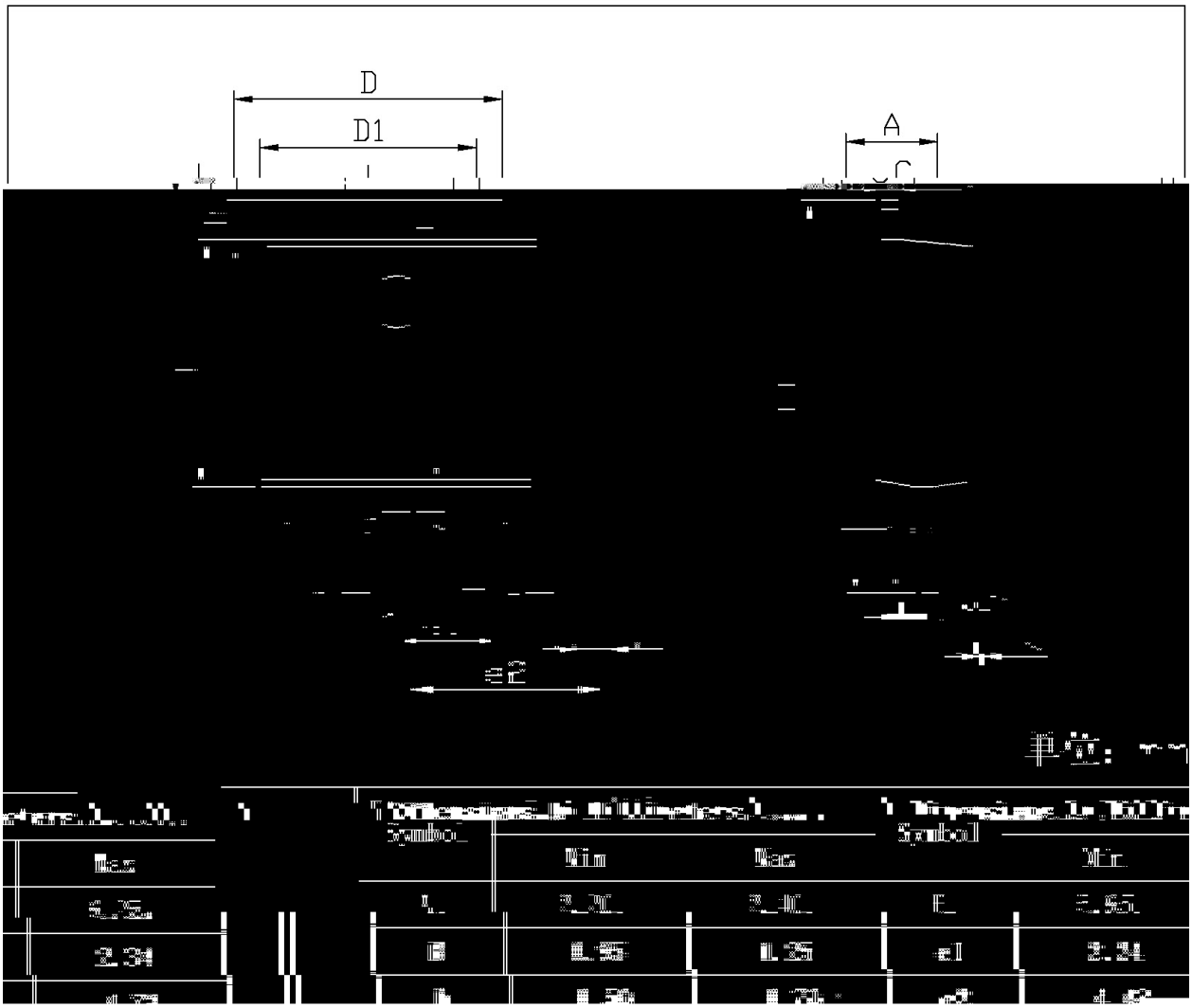
4⁞ IU07 SFE ı 5 ´ и ڤ ı ѡ Ң ấ ɲ ` ų ṕ /FR-4 PCB, 2oz. Copper, minimum recommended pad layout per.

5⁞ Æ ŧ ‖ ˜ ▨╨ : `H ¸ ò lj S Ƈ


IF - TA
IF(A)
12
10
8
6
4
2
0
25
50
75
100
125
150
175
TC N

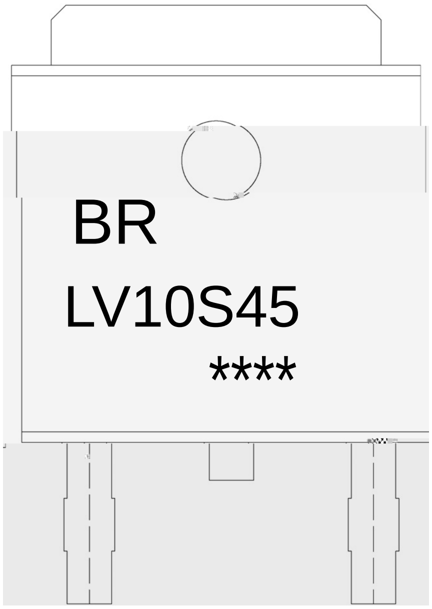

IFSM
8.3ms Single Half Sine
Wave Jedec Method
PEAK FORWARD SURGE CURRENT- (A)
300
275
250
225
200
175
150
125
100
75
50
25
0
0
10
20
30
40
50
60
70
80
90
100
NO.OF CYCLES AT 60HZ





Symbol	Min	Max	Symbol	Min
Max				
5.45	L	9.80	10.40	E
2.34	B	6.45	6.85	e1

TO-252



ب ˝ χ

EU χ ㅉ ʅ ᴻ ℾƀ

0Y43V78 χ ㅉ ʒ ᴺ ℾƀ

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Note:

BR: Company Code

0Y43V78 χ Product Type Code.

****: Lot No. Code, code change with Lot No.